TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1452A

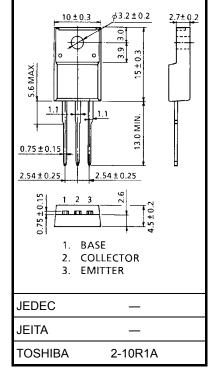
High-Speed, High-Current Switching Applications

Unit: mm

- Low collector saturation voltage: V_{CE} (sat) = -0.4 V (max) (I_{C} = -6 A)
- High-speed switching: $t_{stg} = 1.0 \mu s$ (typ.)
- Complementary to 2SC3710A

Absolute Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-80	V
Collector-emitter voltage	V _{CEO}	-80	V
Emitter-base voltage	V _{EBO}	-6	V
Collector current	Ic	-12	Α
Base current	Ι _Β	-2	Α
Collector power dissipation (Tc = 25°C)	PC	30	W
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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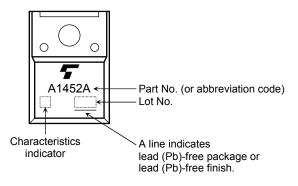


Electrical Characteristics (Tc = 25°C)

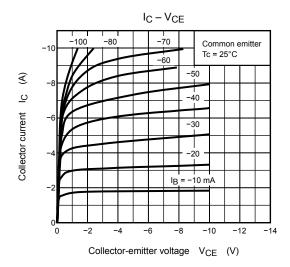
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I _{CBO}	$V_{CB} = -80 \text{ V}, I_E = 0$	_	_	-10	μA
Emitter cut-off cu	rrent	I _{EBO}	V _{EB} = -6 V, I _C = 0		_	-10	μA
Collector-emitter	breakdown voltage	V (BR) CEO	$I_C = -50 \text{ mA}, I_B = 0$	-80	_	_	V
DC current gain	h _{FE (1)} (Note)	V _{CE} = -1 V, I _C = -1 A	70	_	240		
		h _{FE} (2)	V _{CE} = -1 V, I _C = -6 A	40	_	_	
Collector-emitter	saturation voltage	V _{CE} (sat)	I _C = -6 A, I _B = -0.3 A	_	-0.2	-0.4	V
Base-emitter satu	uration voltage	V _{BE} (sat)	I _C = -6 A, I _B = -0.3 A	_	-0.9	-1.2	v
Transition freque	ncy	f _T	V _{CE} = -5 V, I _C = -1 A	_	50	_	MHz
Collector output of	capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	400	_	pF
Switching time Storage time Fall time	t _{on}	20 µs Input B2 Output 20 µs Input B2 G G G G G G G G G G G G G	_	0.3	_		
	t _{stg}		_	1.0	_	μs	
	Fall time	t _f	V_{CC} ≈ -30 V -I _{B1} = I _{B2} = 0.3 A, duty cycle ≤ 1%	_	0.5	_	

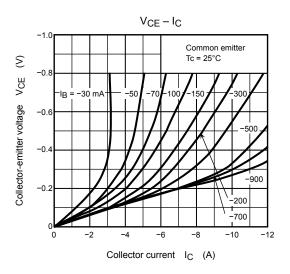
Note: h_{FE} (1) classification O: 70 to 140, Y: 120 to 240

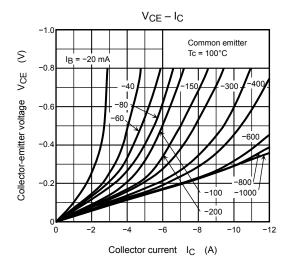
Marking

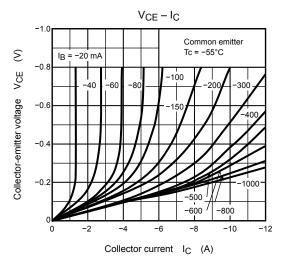


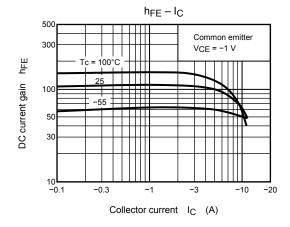
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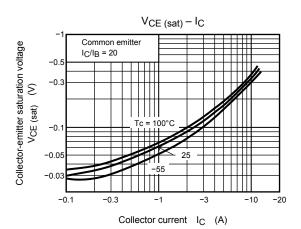




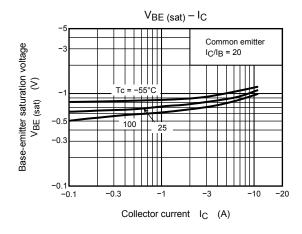


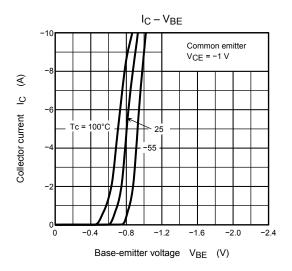


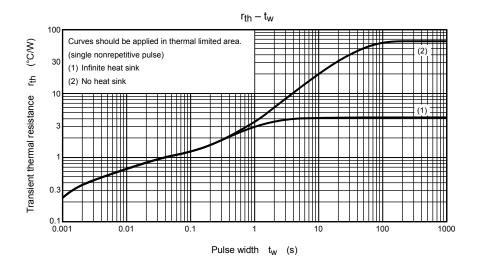




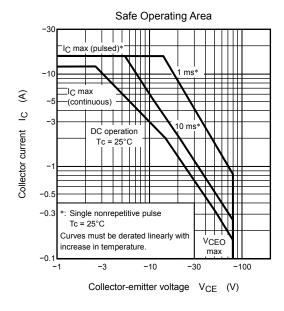
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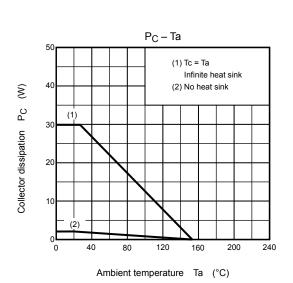






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